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- Choice of phototransistor or photodarlington output
- · Wide lead spacing
- 0.060 in.(1.52 mm)dia. detector aperture
- 0.140 in.(3.56 mm) slot width



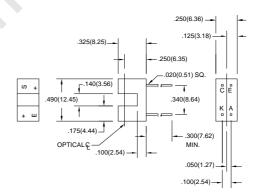
DESCRIPTION

The HOA1883 series consists of an infrared emitting diode facing an NPN silicon phototransistor (HOA1883-011, -012) or photodarlington (HOA1883- 013) encased in a black thermoplastic housing. Detector switching takes place whenever an opaque object passes through the slot between emitter and detector. The HOA1883 series employs plastic molded components. For additional component information see SEP8506, SDP8406, and SDP8106.

Housing material is polycarbonate. Housings are soluble in chlorinated hydrocarbons and ketones. Recommended cleaning agents are methanol and

OUTLINE DIMENSIONS in inches (mm)

Tolerance 3 plc decimals ±0.010(0.25) 2 plc decimals ±0.020(0.51)



DIM_068.ds4

Honeywell

,etAJ.com Honeywell reserves the right to make changes in order to improve design and supply the best products possible.

HOA1883

Transmissive Sensor

ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	TEST CONDITIONS
IR EMITTER						
Forward Voltage	VF			1.6	V	I _F =20 mA
Reverse Leakage Current	I _R			10	μΑ	V _R =3 V
DETECTOR Collector-Emitter Breakdown Voltage HOA1883-011, -012 HOA1883-013	V _(BR) ceo	30 15			V	Ic=100 μA
Emitter-Collector Breakdown Voltage	V _{(BR)ECO}	5.0			V	I _E =100 μA
Collector Dark Current HOA1883-011, -012 HOA1883-013	ICEO			100 250	nA	V _{CE} =10 V I _F =0
COUPLED CHARACTERISTICS On-State Collector Current HOA1883-011 HOA1883-012 HOA1883-013	Ic(on)	0.3 1.8 4.0			mA	VcE=5 V I _F =20 mA
Collector-Emitter Saturation Voltage HOA1883-011 HOA1883-012 HOA1883-013	VCE(SAT)			0.4 0.4 1.1	V	I _F =20 mA I _C =40 μA I _C =230 μA I _C =500 μA
Rise And Fall Time HOA1883-011, -012 HOA1883-013	t _r , t _f		15 75		μs	V_{CC} =5 V, I _C =1 mA R _L =1000 Ω R _L =100 Ω

ABSOLUTE MAXIMUM RATINGS

(25°C Free-Air Temperature unless otherwise noted)

Operating Temperature Range -40°C to 85°C

Storage Temperature Range -40°C to 85°C

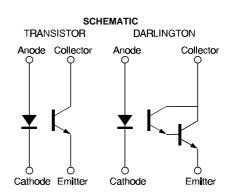
Soldering Temperature (5 sec) 240°C

IR EMITTER

Power Dissipation 100 mW ⁽¹⁾
Reverse Voltage 3 V
Continuous Forward Current 50 mA

DETECTORTRANS.DARLINGTONCollector-Emitter Voltage30 V15 VEmitter-Collector Voltage5 V5 V

Power Dissipation 100 mW ⁽¹⁾ 100 mW ⁽¹⁾



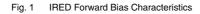
Notes
1. Derate linearly at 0.78 mW/°C above 25°C.

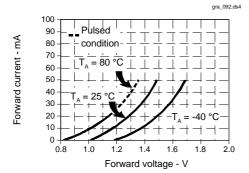
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HOA1883

Transmissive Sensor





Non-Saturated Switching Time vs Load Resistance 1000 ▤◾▦▦ Response time - µs 100 Photodarlington = = = =

ŦI#I#

Collector Current vs

100

10

0.2

0.0

-50

Fig. 4

Phototransistor

Load resistance - Ohms

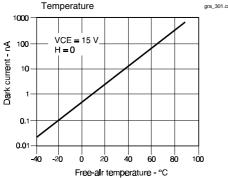
1000

10000

75

100

Dark Current vs Fig. 3



Ambient Temperature gra_095.ds4 Normalized collector current 1.0 0.6 0.4

Ó

25

Free-air temperature - °C

50

All Performance Curves Show Typical Values

HOA1883

Transmissive Sensor

